NSN 5961-01-482-8582

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-482-8582 **Inclosure Material:** Glass **Overall Length:** 0.180 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.080 inches **Function For Which Designed:** Switching **End Application:** Kg-228 (crypto) **Mounting Method: Terminal Criticality Code Justification: Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 breakdown voltage, dc and 125.00 working peak reverse voltage **Current Rating Per Characteristic:** 300.00 milliamperes forward current, average absolute and 2.50 amperes forward current, average preset **Capacitance Rating In Picofarads:** 2.5 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Electrostatic discharge sensitive; aero-space applications **Test Data Document:** Mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/578 government specification Shelf Life: N/a **Unit Of Measure:**

NSN 5961-01-482-8582

Diode Semiconductor Device - Page 2 of 2



Mil-std (military Standard):

Mil-prf-19500 spec.